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Title of the Invention:

CAPACITOR ELEMENT OF SOLID ELECTROLYTIC CAPACITOR, METHOD OF
MAKING THE CAPACITOR ELEMENT, AND SOLID ELECTROLYTIC CAPACITOR
USING THE CAPACITOR ELEMENT
DECLARATION

I, kyoko NAKAGAWA, hereby declare:

that I am a translator belonging to KYOWEY INT'L of
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that I am well acquainted with both the Japanese and English
languages;

that, for entering the national phase of the
above-identified international application, I have prepared an
English translation of the Japanese specification and claims
as originally filed with the Japanese Patent Office (Receiving
Office); and

that the said English translation corresponds to the said
Japanese specification and claims to the best of my knowledge.

I also declare that all statements made herein of my
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Declared at Osaka, Japan on December 20, 2004

By Kyoko NAKAGAWA

Signature *Kyoko Nakagawa*

SPECIFICATION

CAPACITOR ELEMENT OF SOLID ELECTROLYTIC CAPACITOR, METHOD OF
MAKING THE CAPACITOR ELEMENT, AND SOLID ELECTROLYTIC CAPACITOR

5 USING THE CAPACITOR ELEMENT

BACKGROUND OF THE INVENTION

The present invention relates to a solid electrolytic capacitor utilizing valve metal such as tantalum, niobium or 10 aluminum, for example. The invention particularly relates to a capacitor element used for such a capacitor, a method of making such a capacitor element, and a solid electrolytic capacitor using such a capacitor element.

Conventionally, a capacitor element for use in the above 15 kind of solid electrolytic capacitor is manufactured by such a method as disclosed in JP-A 7-66079, for example. This method comprises the following process steps.

(1) As shown in Fig. 1, powder of valve metal such as tantalum is compacted into a porous parallelepiped anode chip body 2 so that an anode wire 3 projects from a first end surface 2a of the porous chip body 2. Then, the anode chip body is sintered.

(2) Subsequently, the anode chip body 2 is subjected to anodizing. Specifically, direct current is applied, with the anode chip body immersed in a chemical solution such as an aqueous solution 25 of phosphoric acid. As a result, a dielectric film of e.g. tantalum pentoxide is formed on each metal particle of the anode chip body.

(3) Subsequently, as shown in Fig. 1, the anode chip body 2,

(3) Subsequently, as shown in Fig. 1, the anode chip body 2, with the anode wire 3 oriented upward, is immersed into an electrolyte solution A such as an aqueous solution of manganese nitrate so that the electrolyte solution A infiltrates into
5 the porous structure of the anode chip body 2. Thereafter, the anode chip body 2 is pulled out from the electrolyte solution A, and dried and baked. These process steps are repeated a plurality of times. As a result, as shown in Figs. 2 and 3, a solid electrolyte layer 4 made of metal oxide such as manganese
10 dioxide is formed at the surfaces of the anode chip body 2 via the dielectric film.

(4) Subsequently, a graphite layer is formed at the surfaces of the anode chip body 2 except the end surface 2a.

(5) Then, with the anode wire 3 oriented upward again, the anode
15 chip body 2 is immersed in a metal paste such as silver paste and then pulled out and baked. As a result, as shown in Fig. 4, a cathode electrode film 5 of the metal paste is formed at the surfaces of the anode chip body 2 except the first end surface 2a.

20 In this way, a capacitor element 1 is manufactured.

However, in the process step for forming a solid electrolyte layer 4 of metal oxide such as manganese dioxide on the anode chip body 2 via the dielectric film, when the anode chip body 2 is pulled out of the electrolyte solution A, an excess of
25 the electrolyte solution caused to infiltrate into the porous structure of the anode chip body 2 drips from a second end surface 2b, i.e. the lower end surface of the anode chip body 2.

When the excess of the electrolyte solution drips from the second end surface 2b of the anode chip body 2, part of the solution gathers to form droplets, by surface tension, at all of four corner edges 2c', 2d', 2e' and 2f' of the anode 5 chip body 2 where four side surfaces 2c, 2d, 2e and 2f meet the second end surface 2b. Since the anode chip body is dried and baked in this state, the solid electrolyte layer 4 formed by the above step includes outwardly projecting bumps at all the four corner edges 2c', 2d', 2e' and 2f' surrounding the 10 second end surface 2b while recessing at the center of the second end surface 2b, as shown in Figs. 2 and 3.

In this way, the bumps 4' of the solid electrolyte layer 4 surrounds the second end surface 2b of the anode chip body 2 along the entire periphery of the end surface. Following 15 the above step, after a graphite layer is formed on the anode chip body 2, the anode chip body 2 is immersed in a metal paste such as a silver paste with the anode wire 3 oriented upward and then baked for forming a cathode-side electrode film 5, as shown in Fig. 4. However, when the anode chip body 2 is 20 immersed in a metal paste in the step of forming a cathode-side electrode film, air cannot escape from the recessed portion of the solid electrolyte layer 4 at the second end surface 2b. Therefore, a void is formed due to the trapping of an air bubble 6, which probably causes a defect in the product.

25 When the cathode-side electrode film 5 is formed to overlap the solid electrolyte layer 4, the cathode-side electrode film 5 also bulges at the four corner edges 2c', 2d', 2e' and 2f'

to form bumps 5' overlapping the bumps 4' of the solid electrolyte layer 4.

In this way, the solid electrolyte layer 4 and the cathode-side electrode film 5 are bulged to form bumps 4' and 5' at all of the corner edges 2c', 2d', 2e' and 2f' surrounding the second end surface 2b of the capacitor element 1. The capacitor element 1 is thereafter disposed between an anode lead terminal and a cathode lead terminal so that the anode wire 3 is connected to the anode lead terminal while the cathode-side electrode film 5 is connected to the cathode lead terminal, and the entirety is sealed in a package to provide a complete package-type solid electrolytic capacitor. However, the height and width of the package need be increased by as much as the dimension of the bumps 4' and 5' formed at the corner edges 2c', 2d', 2e' and 2f' surrounding the second end surface 2b of the anode chip body, whereby the size and weight of the capacitor is disadvantageously increased.

DISCLOSURE OF THE INVENTION

An object of the present invention is to provide a capacitor element capable of solving the above-described problems without reducing the capacitance of a capacitor and to provide a method for making such a capacitor element and a solid electrolytic capacitor utilizing such a capacitor element.

To achieve the above object, the present invention provides a capacitor element comprising: an anode chip body including a porous sintered body formed by sintering valve metal powder

into a rectangular parallelepiped having four side surfaces, a first end surface and a second end surface which is opposite from the first end surface, and an anode wire fixed to the first end surface; a dielectric film formed on the metal powder of 5 the anode chip body; a solid electrolyte layer formed on the dielectric film; and a cathode-side electrode film formed on the anode chip body via the solid electrolyte film. In the capacitor element, at least two of four edges of the anode chip body at which the four side surfaces meet the second end surface 10 are rounded or chamfered, the two edges being parallel with each other.

A method of making a capacitor element according to the present invention comprises the steps of: preparing an anode chip body including a porous sintered body formed by sintering 15 valve metal powder into a rectangular parallelepiped having four side surfaces, a first end surface and a second end surface which is opposite from the first end surface, and an anode wire fixed to the first end surface, the anode chip body being so formed that at least two of four edges at which the four side 20 surfaces meet the second end surface are chamfered or rounded, the two edges being parallel with each other; forming a dielectric film on the metal powder of the anode chip body; forming a solid electrolyte layer by immersing the anode chip body in an electrolyte solution with the anode wire oriented upward, 25 pulling the anode chip body from the solution followed by baking the anode chip body; and forming a cathode-side electrode film of a metal paste on the anode chip body via the solid electrolyte

layer.

A solid electrolytic capacitor according to the present invention comprises an anode lead terminal plate, a cathode lead terminal plate, and a capacitor element arranged between

5 the anode lead terminal plate and the cathode lead terminal plate; the capacitor element comprising an anode chip body including a porous sintered body formed by sintering valve metal powder into a rectangular parallelepiped having four side surfaces, a first end surface and a second end surface which

10 is opposite from the first end surface, and an anode wire fixed to the first end surface, a dielectric film formed on the metal powder of the anode chip body, a solid electrolyte layer formed on the dielectric film, and a cathode-side electrode film formed on the anode chip body via the solid electrolyte film; the anode

15 wire of the capacitor element being fixed to the anode lead terminal plate, the cathode-side electrode film being electrically connected to the cathode lead terminal plate. At least two of four edges of the anode chip body at which the four side surfaces meet the second end surface are rounded or

20 chamfered, the two edges being parallel with each other.

In this way, of the four edges at which the four side surfaces meet the second end surface of the anode chip body, at least two edges which are parallel with each other are rounded or chamfered. Therefore, in the above step for forming a solid

25 electrolyte layer on the anode chip body via the dielectric film, when the anode chip body is pulled out from the electrolyte solution, the electrolyte solution dripping from the second,

or the lower end surface of the anode chip body gathers to form droplets only at the remaining two of the four edges surrounding the second end surface, i.e. at the two corner edges which are not rounded nor chamfered. The electrolyte solution does not
5 gather to form droplets at the two rounded or chamfered edges. Accordingly, the solid electrolyte layer formed on the anode chip body is reliably prevented from bulging to form bumps at the two edges which are rounded or chamfered.

Specifically, the electrolyte layer formed on the anode
10 chip body bulges into bumps only at two edges, which are parallel with each other, of the four edges surrounding the second end surface. Therefore, at the second end surface of the anode chip body, the electrolyte layer is prevented from being surrounded by the outwardly projecting bumps along the entire
15 periphery of the end surface. Therefore, when the anode chip body is subsequently immersed in a metal paste such as a silver paste for forming a cathode-side electrode film, air at the second end surface of the anode chip body can easily escape. Therefore, trapping of air at that portion is less likely to
20 occur, whereby the formation of a void due to the trapping of an air bubble can be prevented in forming the cathode electrode film of a metal paste such as a silver paste. Therefore, the production of a defective capacitor element is reliably reduced.

Further, of the four edges surrounding the second end
25 surface of the anode chip body, the formation of the outward bumps of the solid electrolyte layer and the cathode-side electrode film can be limited to the corner edges other than

at least two edges which are rounded or chamfered. Therefore,
when the capacitor element is assembled into a packaged-type
solid electrolytic capacitor as will be described in the
description of embodiments, either the height or width of the
5 package-type solid electrolytic capacitor can be reduced by
as much as the dimension of the bumps of the solid electrolyte
layer and the cathode-side electrode film which do not project
from at least two rounded or chamfered edges of the anode chip
body. As a result, the size and weight of the solid electrolytic
10 capacitor can be reduced.

Particularly, when only two edges are rounded or chamfered
as set forth in Claim 2, a reduction in the volume of the anode
chip can be suppressed as compared with the case where all of
the four edges are rounded or chamfered, whereby a larger reduction
15 in the capacitance of the capacitor element can be prevented.

Moreover, when the structure as set forth in Claim 5 is
employed, the bumps of the solid electrolyte layer and the
cathode-side electrode film formed at the second end surface
of the capacitor element are prevented from coming into contact
20 with the cathode-side lead terminal plate. Therefore, damage
to the bumps such as chipping off of the bumps can be reliably
prevented, and the cathode lead film can be electrically
connected to the cathode-side lead terminal plate reliably.

25 BRIEF DESCRIPTION OF THE DRAWINGS

Fig. 1 is a perspective view showing an anode chip body
of a prior art capacitor element.

Fig. 2 is a longitudinal sectional view showing the prior art anode chip body on which a solid electrolyte layer is formed.

Fig. 3 is a sectional view taken along lines III-III in Fig. 2.

5 Fig. 4 is a longitudinal sectional view showing the prior art capacitor element.

Fig. 5 is a perspective view showing an anode chip body of a capacitor element according to the present invention.

10 Fig. 6 is a sectional view taken along lines VI-VI in Fig. 5.

Fig. 7 is a sectional view taken along lines VII-VII in Fig. 5.

15 Fig. 8 is a perspective view showing another example of anode chip body of a capacitor element according to the present invention.

Fig. 9 is a longitudinal sectional view showing the anode chip body formed with a solid electrolyte layer according to the present invention.

20 Fig. 10 is a sectional view taken along lines X-X in Fig. 9.

Fig. 11 is a longitudinal sectional view showing a capacitor element according to the present invention.

Fig. 12 is a sectional view taken along lines XII-XII in Fig. 11.

25 Fig. 13 is a longitudinal sectional view showing a solid electrolytic capacitor made by using the capacitor element according to the present invention.

Fig. 14 is a sectional view taken along lines XIV-XIV in Fig. 13.

DETAILED DESCRIPTION OF THE PREFERRED EMBODIMENTS

5 Preferred embodiments of the present invention will be described below with reference to the accompanying drawings (Figs. 5-13) showing a capacitor element for a tantalum solid electrolytic capacitor according to the present invention.

Fig. 5 shows an anode chip body 12 formed by compacting 10 tantalum powder into a rectangular parallelepiped followed by sintering. The anode chip 12 includes a first end surface 12a to which an anode wire 13 made of tantalum is fixed to project therefrom.

The anode chip body 12 is rectangular with a longer side 15 D1 and a shorter side D2 in a cross section perpendicular to the anode wire 13 and has a height L.

In forming the anode chip body 12 by compacting, the two ridge lines, i.e., corner edges where the opposite pair of larger side surfaces 12c and 12e of the four side surfaces 12c, 12d, 20 12e and 12f of the anode chip body meet a second end surface 12b which is opposite from the first end surface 12a are chamfered to provide beveled surfaces 12g and 12h, as shown in Figs. 5 and 6, or rounded to provide rounded surfaces 12g' and 12h', as shown in Fig. 8.

25 Similarly to the prior art method, the anode chip body 12 is subjected anodizing, i.e., subjected to direct current application with the anode chip body immersed in a chemical

solution such as an aqueous solution of phosphoric acid. As a result, a dielectric film of e.g. tantalum pentoxide is formed on each metal particle of the anode chip body 12.

Subsequently, similarly to the case shown in Fig. 1, the
5 anode chip body 12, with the anode wire 13 oriented upward,
is immersed in an electrolyte solution such as an aqueous solution
of manganese nitrate so that the electrolyte solution
infiltrates into the porous structure in the anode chip body
12. Thereafter, the anode chip body 12 pulled out from the
10 electrolyte solution is dried and baked. These process steps
are repeated a plurality of times. As a result, as shown in
Figs. 9 and 10, a solid electrolyte layer 14 made of metal oxide
such as manganese dioxide is formed on the anode chip body 12
via the dielectric film.

15 In the above step for forming the solid electrolyte layer
14 on the anode chip body 12 via the dielectric film, when the
anode chip body 14 is pulled out from the electrolyte solution,
the electrolyte solution dripping from the second, or the lower
end surface 12b of the anode chip body 12 gathers to form droplets
20 only at the two ridge lines, i.e. the two corner edges 12i and
12j where the opposite pair of smaller side surfaces 12d and
12f of the four side surfaces 12c, 12d, 12e and 12f of the anode
chip body 12 meet the second end surface 12b. The electrolyte
solution does not gather to form droplets at the two beveled
25 surfaces 12g, 12h or rounded surfaces 12g', 12h'.

Therefore, of the four edges surrounding the second end
surface 12b, only the corner edges 12i and 12j which are not

chamfered or rounded unlike the surfaces 12g, 12g or the surfaces 12g', 12h' are formed with bumps 14' of the electrolyte layer 14. In this way, at the second end surface 12b of the anode chip body 12, the electrolyte layer 14 is prevented from being 5 surrounded by the outwardly projecting bumps 14' along the entire periphery of the end surface.

Subsequently, after a graphite layer as an underlying layer is formed on the anode chip body 12, the anode chip body 12 is immersed in a metal paste such as a silver paste with the 10 anode wire 13 oriented upward and then pulled out and baked. As a result, as shown in Figs. 11 and 12, a cathode-side electrode film 15 of the metal paste is formed on the surfaces of the anode chip body 12 except the first end surface 12a, whereby a capacitor element 11 is provided.

15 When the anode chip body 12 is immersed in the metal paste for forming the cathode-side electrode film 15, air at the second end surface 12b of the anode chip body 12 can easily escape so that trapping of air at that portion is unlikely to occur. Therefore, in forming the cathode-side electrode film 15 by 20 using a metal paste such as a silver paste, the formation of a void due to the trapping of an air bubble can be prevented.

At the second end surface 12b of the anode chip body 12, the cathode electrode film 15 formed in the above manner bulges to become bumps 15' only at portions overlapping the outward 25 bumps 14' of the solid electrolyte layer 14. Thus, of the four edges of the second end surface 12b, the cathode electrode film 15 is prevented from bulging to become bumps at the beveled

surfaces 12g, 12h or the rounded surfaces 12g', 12h'.

The capacitor element 11 made in the above manner is assembled into a package-type solid electrolytic capacitor 100 in the following manner.

5 As shown in Figs. 13 and 14, the capacitor element 11 is placed between a pair of lead terminal plates 16 and 17 so that a parallel pair of larger side surfaces 12c, 12e of the four side surfaces 12c, 12d, 12e, 12f of the anode chip body 12 extend in parallel or generally in parallel with obverse surfaces of
10 the lead terminal plates 16, 17. The anode wire 13 of the capacitor element 11 is bonded to the anode-side lead terminal plate 16 by e.g. welding, whereas the cathode-side lead terminal 17 is electrically connected directly to the cathode-side electrode film 15 of the capacitor element 11 using a conductive
15 paste 18, for example. Subsequently, the entirety is hermetically sealed in a package 19, whereby a package-type solid electrolytic capacitor 100 is provided.

In this structure, the outward bumps 14', 15' of the solid electrolyte layer 14 and the cathode-side electrode film 15 formed at the second end surface 12b of the anode chip body 12 do not project from the side surfaces 12c and 12e which, of the four side surfaces 12c, 12d, 12e and 12f of the anode chip body, become an upper surface and a lower surface, respectively, when the anode chip body is assembled into the
25 capacitor. Therefore, the height H of the package-type solid electrolytic capacitor 100 can be reduced by as much as the dimension of the bumps 14', 15' which do not project from the

surfaces 12c, 12e, whereby the size and weight of the capacitor can be reduced.

Since the bumps 14' and 15' do not project from the side surfaces 12c and 12e, the bumps 14' and 15' do not come into contact with the cathode-side lead terminal plate 17. Therefore, in assembling the solid electrolytic capacitor, damage to the bumps 14' and 15' such as chipping off of the bumps can be avoided, and the cathode-side electrode film 15 can be electrically connected to the cathode-side lead terminal plate 17 reliably.

In assembling the solid electrolytic capacitor, the capacitor element 11 may be placed so that, of the four side surfaces 12c, 12d, 12e and 12f of the anode chip body 12, the side surfaces 12d and 12f, which are not formed into beveled surfaces 12g, 12h or rounded surfaces 12g', 12h' at the edges meeting the second end surface 12b, become parallel or generally parallel with the obverse surfaces of the lead terminal plates 16 and 17. In such a case, the width W of the solid electrolytic capacitor 100 can be reduced.